

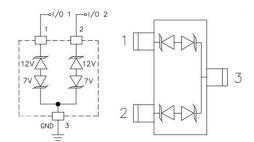
Asymmetrical TVS Diode Array

FEATURES:

- ♦ Ultra low leakage: nA level
- ♦ Operating voltage: 7V or 12V
- ♦ Low clamping voltage
- ♦ Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test

Air discharge: ±15kV Contact discharge: ±8kV

- IEC61000-4-5 (Lightning) 13A for 12V (8/20μs)– IEC61000-4-5 (Lightning) 18A for 7V (8/20μs)



SOT-23

PIN Configuration

MAIN APPLICATIONS

- Protection of RS-485 transceivers with extended common-mode range
- ♦ Security systems
- ♦ Automatic Teller Machines
- ♦ HFC systems
- ♦ Networks

MECHANICAL CHARACTERISTICS

♦ Package SOT-23

Molding Compound Flammability Rating: UL 94V-O

♦ Quantity Per Reel : 3,000pcs♦ Lead Finish : Lead Free

♦ Marking: 712

ABSOLUTE MAXIMUM RATINGS (T_A=25°C, RH=45%-75%, unless otherwise noted)

Parameter	Symbol	Value	Unit
Peak Pulse Power (tp = 8/20μs),(V _{RWM} =7V/V _{RWM} =12V)	P _{PPM}	360	W
Peak Pulse Current (tp = 8/20μs),(V _{RWM} =7V/V _{RWM} =12V)	I _{PPM}	18/13	Α
ESD voltage IEC 61000-4-2 (air discharge)	V _{ESD}	15	kV
ESD voltage IEC 61000-4-2 (contact discharge)	V _{ESD}	8	kV
Maximum lead temperature for soldering during 10s	TL	260	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C
Operating Temperature Range	T _{OP}	-55 to +125	°C

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Electrical Characteristics (TA=25°C unless otherwise specified)

Parameter	Symbol	Min	Тур	Max	Unit	Condition
Reverse Working Voltage	V _{RWM}			7.0	V	Pin3 to Pin1 or 2
				12.0		Pin1 or 2 to Pin3
Proakdown Voltago		7.5			V	I _T =1mA,Pin3 to Pin1 or 2
Breakdown Voltage	V_{BR}	13.3				I _T =1mA,Pin1 or 2 to Pin3
Leakage Current ILeak	ı			1.0	μΑ	V _{RWM} =7V,Pin3 to Pin1 or 2
	l _R			1.0		V _{RWM} =12V,Pin1 or 2 to Pin3
Clamping Voltage	Vc			20.0	V	I _{PP} =18A,T _p =8/20μs,Pin3 to Pin1 or 2
				30.0		I _{PP} =13A,T _p =8/20μs,Pin1 or 2 to Pin3
Junction Capacitance	CJ		45.0		рF	V _R =0V, f=1MHz,Pin1 or 2 to Pin3

Characteristic Curves

FIG.1:V- I curve characteristics (Bi-directional)

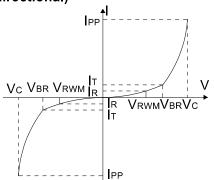


FIG.3: Pulse derating curve

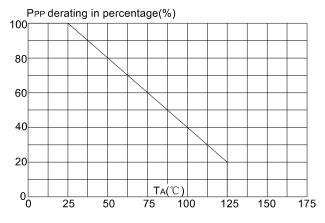


FIG.2: Pulse waveform (8/20µs)

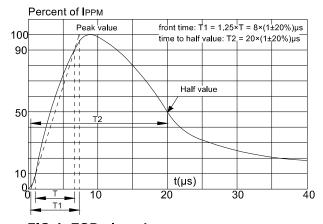
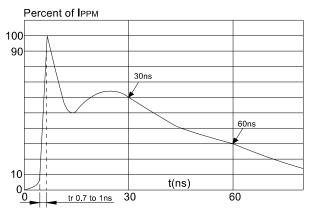


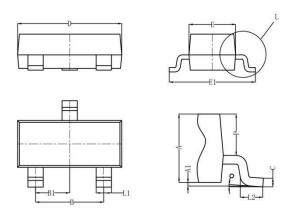
FIG.4: ESD clamping (8KV contact)





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PACKAGE MECHANICAL DATA

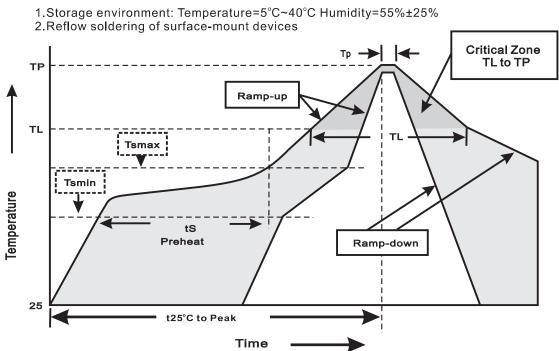


Sumbol	Dimensions (mm)						
Symbol	Min	Тур	Max				
А	0.900	1.000	1.1100				
A1	0.000	0.050	0.100				
L1	0.350	0.400	0.500				
С	0.100	0.110	0.120				
D	2.800	2.900	3.000				
E	1.250	1.300	1.350				
E1	2.250	2.400	2.550				
В	1.800	1.900	2.000				
B1	0.950 Typ						
L2	0.200	0.350	0.450				
Р	0.550	0.575	0.600				



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Suggested thermal profiles for soldering processes



3.Reflow soldering

Profile Feature	Soldering Condition	
Average ramp-up rate(T∟ to T♭)	<3°C/sec	
Preheat -Temperature Min(Tsmin) -Temperature Max(Tsmax) -Time(min to max)(t _s)	150°C 200°C 60~120sec	
Tsmax to T∟ -Ramp-upRate	<3°C/sec	
Time maintained above: -Temperature(TL) -Time(tL)	217°C 60~260sec	
Peak Temperature(T _P)	255°C-0/+5°C	
Time within 5°C of actual Peak Temperature(t _P)	10~30sec	
Ramp-down Rate	<6°C/sec	
Time 25°C to Peak Temperature	<6minutes	